

DATA SHEET

BT152 series Thyristors

Product specification

September 2019



WeEn
WeEn Semiconductors

Thyristors

BT152 series

GENERAL DESCRIPTION

Planar passivated thyristors in a plastic envelope, intended for use in applications requiring high bidirectional blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

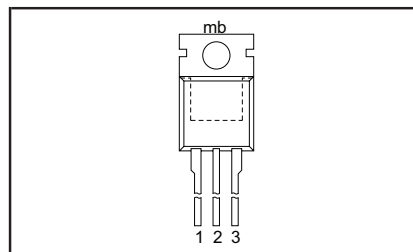
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BT152-	400R	600R	800R	
V_{DRM}	Repetitive peak off-state voltages	450	650	800	V
V_{RRM}	Average on-state current	13	13	13	A
$I_{T(AV)}$	RMS on-state current	20	20	20	A
$I_{T(RMS)}$	Non-repetitive peak on-state current	200	200	200	A
I_{TSM}					

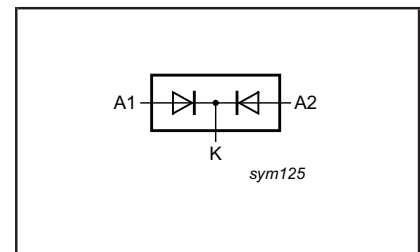
PINNING - TO220AB

PIN	DESCRIPTION
1	cathode
2	anode
3	gate
tab	anode

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V_{DRM}	Repetitive peak off-state voltages		-	-400R 450 ¹	-600R 650 ¹	-800R 800	V
$I_{T(AV)}$	Average on-state current	half sine wave; $T_{mb} \leq 103\text{ }^{\circ}\text{C}$	-	13			A
$I_{T(RMS)}$	RMS on-state current	all conduction angles	-	20			A
I_{TSM}	Non-repetitive peak on-state current	half sine wave; $T_j = 25\text{ }^{\circ}\text{C}$ prior to surge	-	200			A
		$t = 10\text{ ms}$	-	220			A
I^2t	I^2t for fusing	$t = 8.3\text{ ms}$	-	200			A^2s
dI_T/dt	Repetitive rate of rise of on-state current after triggering	$t = 10\text{ ms}$	-	200			$\text{A}/\mu\text{s}$
		$I_{TM} = 50\text{ A}; I_G = 0.2\text{ A}; dI_G/dt = 0.2\text{ A}/\mu\text{s}$	-	200			
I_{GM}	Peak gate current		-	5			A
V_{GM}	Peak gate voltage		-	5			V
V_{RGM}	Peak reverse gate voltage		-	5			V
P_{GM}	Peak gate power		-	20			W
$P_{G(AV)}$	Average gate power	over any 20 ms period	-	0.5			W
T_{stg}	Storage temperature		-40	150			$^{\circ}\text{C}$
T_j	Operating junction temperature		-	125			$^{\circ}\text{C}$

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μs .

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BT152 series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	in free air	-	-	1.1	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient		-	60	-	K/W

STATIC CHARACTERISTICS

 $T_j = 25\ ^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{GT}	Gate trigger current	$V_D = 12\ \text{V}; I_T = 0.1\ \text{A}$	-	3	32	mA
I_L	Latching current	$V_D = 12\ \text{V}; I_{GT} = 0.1\ \text{A}$	-	25	80	mA
I_H	Holding current	$V_D = 12\ \text{V}; I_{GT} = 0.1\ \text{A}$	-	15	60	mA
V_T	On-state voltage	$I_T = 40\ \text{A}$	-	1.4	1.75	V
V_{GT}	Gate trigger voltage	$V_D = 12\ \text{V}; I_T = 0.1\ \text{A}$	-	0.6	1.5	V
I_D, I_R	Off-state leakage current	$V_D = V_{DRM(max)}; I_T = 0.1\ \text{A}; T_j = 125\ ^\circ\text{C}$	0.25	0.4	-	V
		$V_D = V_{DRM(max)}; V_R = V_{RRM(max)}; T_j = 125\ ^\circ\text{C}$	-	0.2	1.0	mA

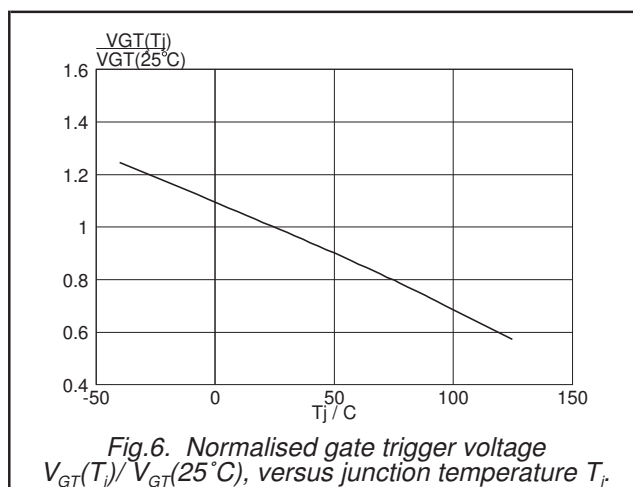
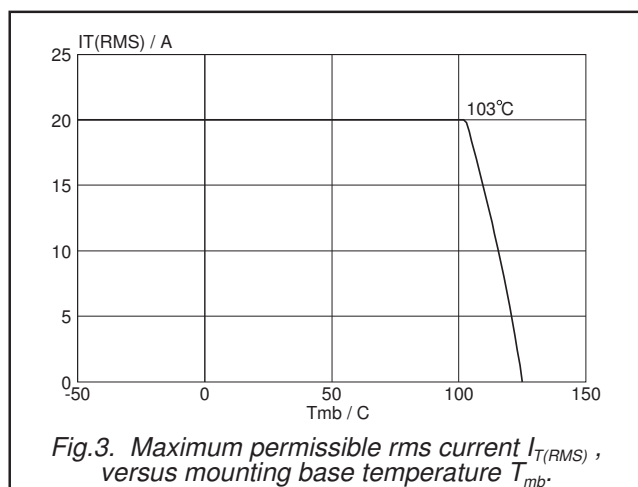
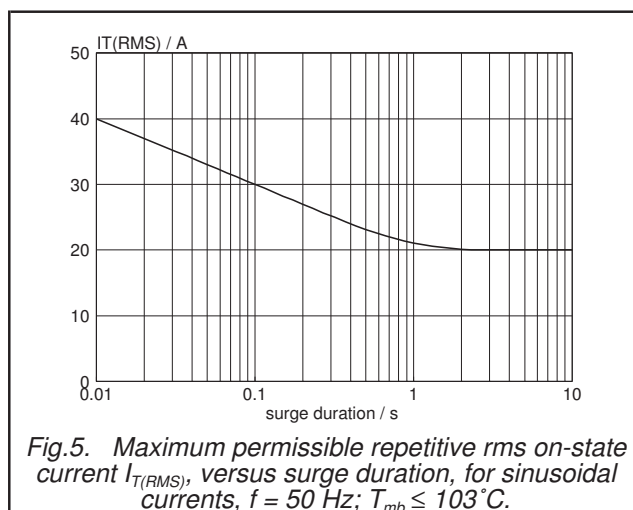
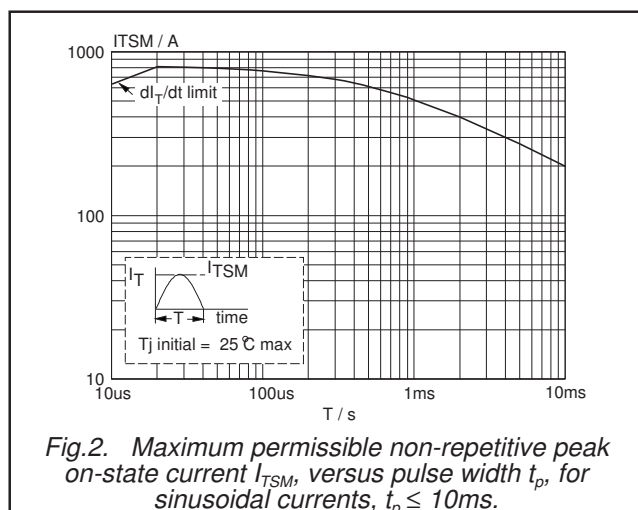
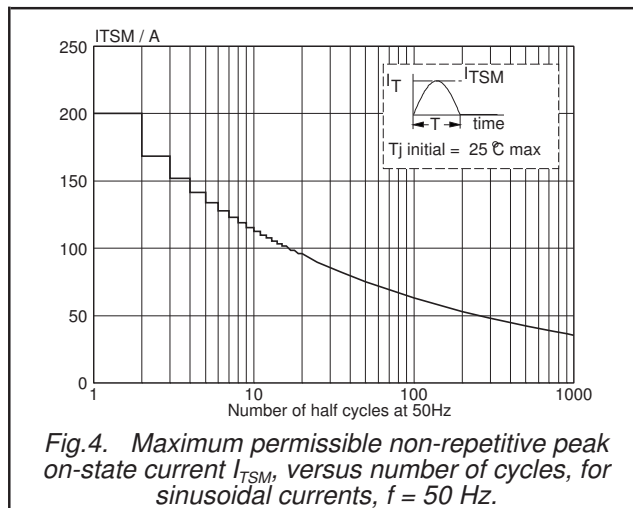
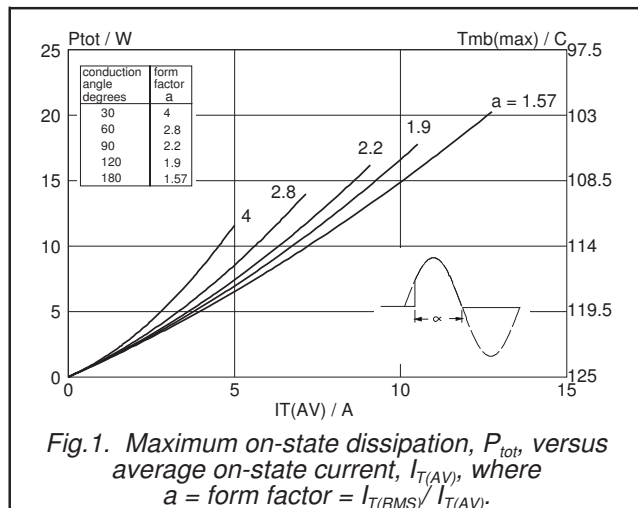
DYNAMIC CHARACTERISTICS

 $T_j = 25\ ^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV_D/dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125\ ^\circ\text{C};$ exponential waveform gate open circuit	200	300	-	V/ μs
t_{gt}	Gate controlled turn-on time	$V_D = V_{DRM(max)}; I_G = 0.1\ \text{A}; dI_G/dt = 5\ \text{A}/\mu\text{s};$ $I_{TM} = 40\ \text{A}$	-	2	-	μs
t_q	Circuit commutated turn-off time	$V_D = 67\% V_{DRM(max)}; T_j = 125\ ^\circ\text{C};$ $I_{TM} = 50\ \text{A}; V_R = 25\ \text{V}; dI_{TM}/dt = 30\ \text{A}/\mu\text{s};$ $dV_D/dt = 50\ \text{V}/\mu\text{s}; R_{GK} = 100\ \Omega$	-	70	-	μs

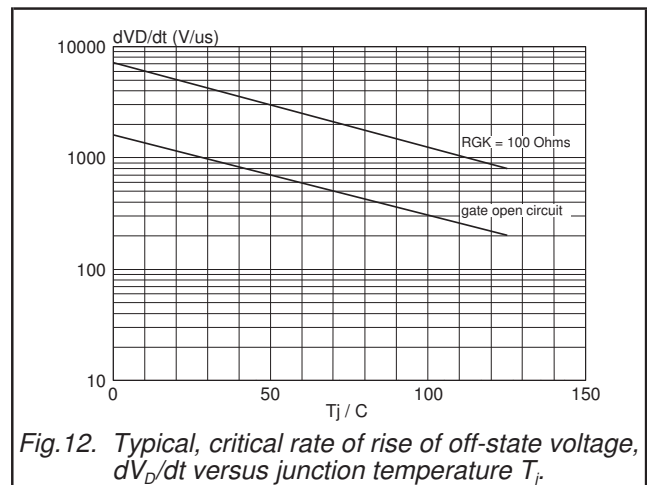
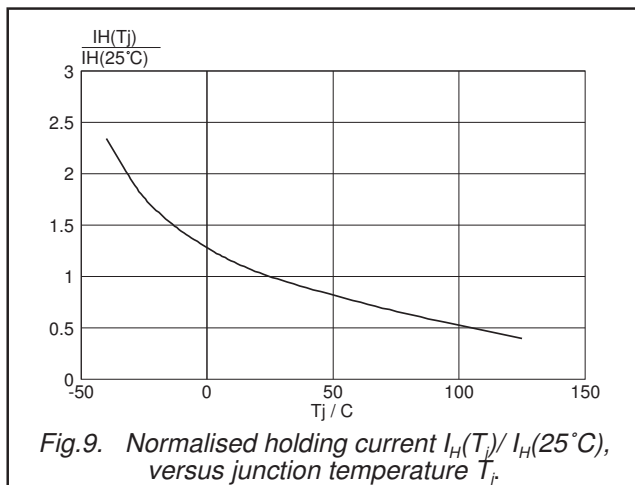
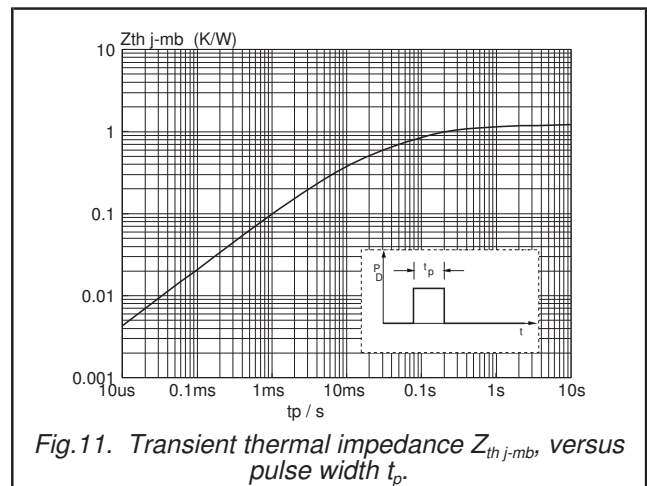
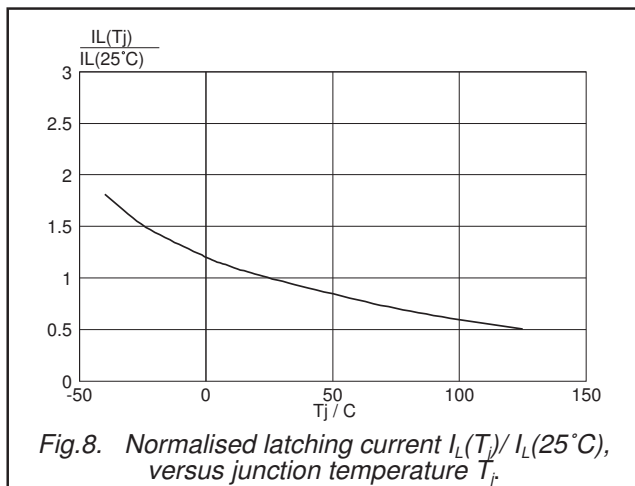
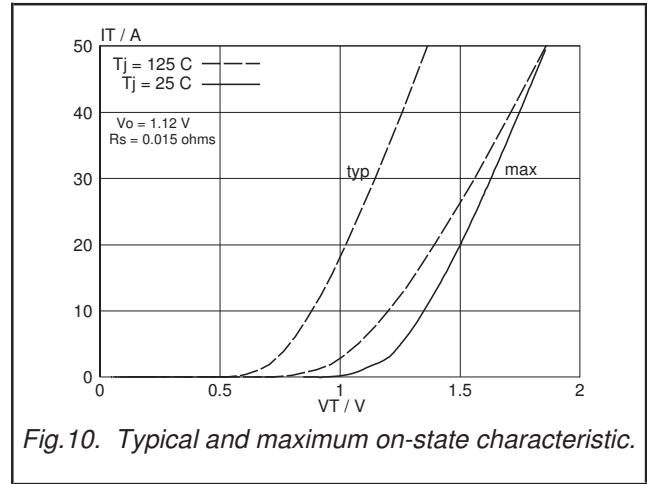
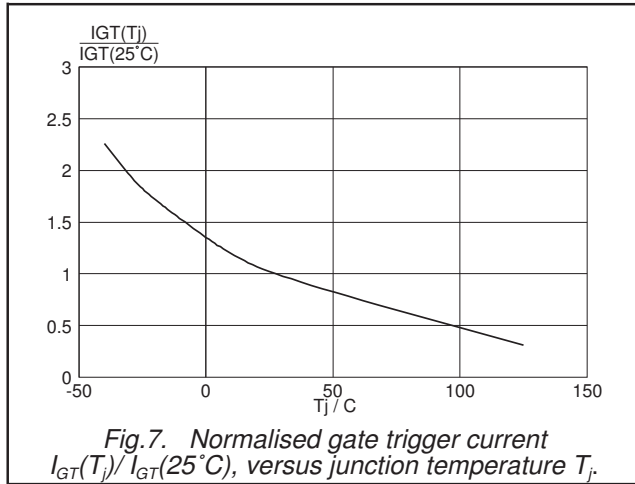
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BT152 series



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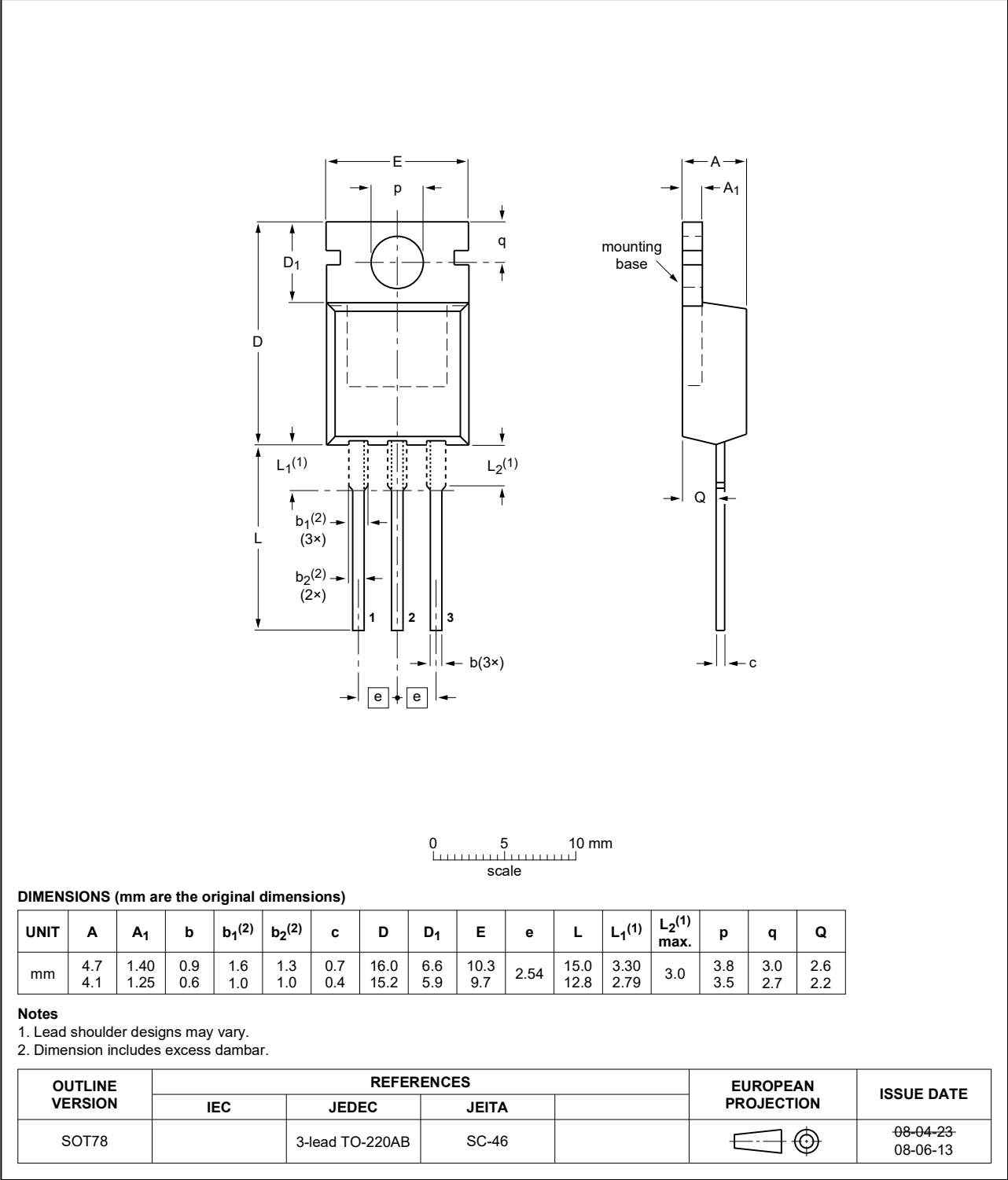
Thyristors

BT152 series

MECHANICAL DATA

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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